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Mid-Frequency Noise Coupling between DC-DC Converters and High-Speed Signals

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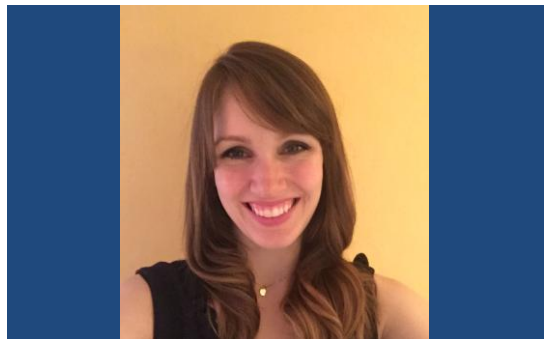
Speaker

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Laura Kocubinski is a Hardware Engineer at Oracle Corp. She currently works on signal and power integrity within Oracle's SPARC server division. She received her BSEE from Rensselaer Polytechnic Institute.



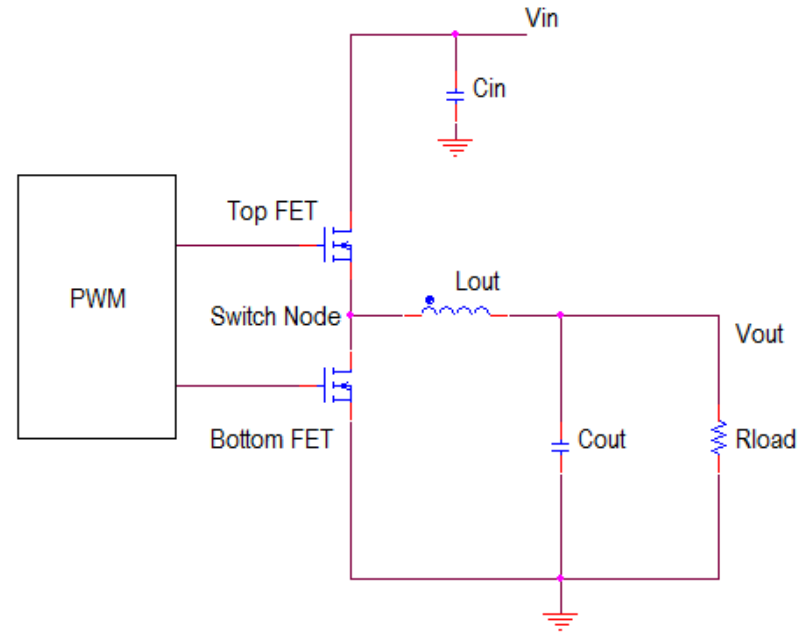
Outline

- Introduction
- Background: Problem Discovery
- Debugging a Solution
- Proof of Solution
- Understanding the Noise Source
- Conclusion



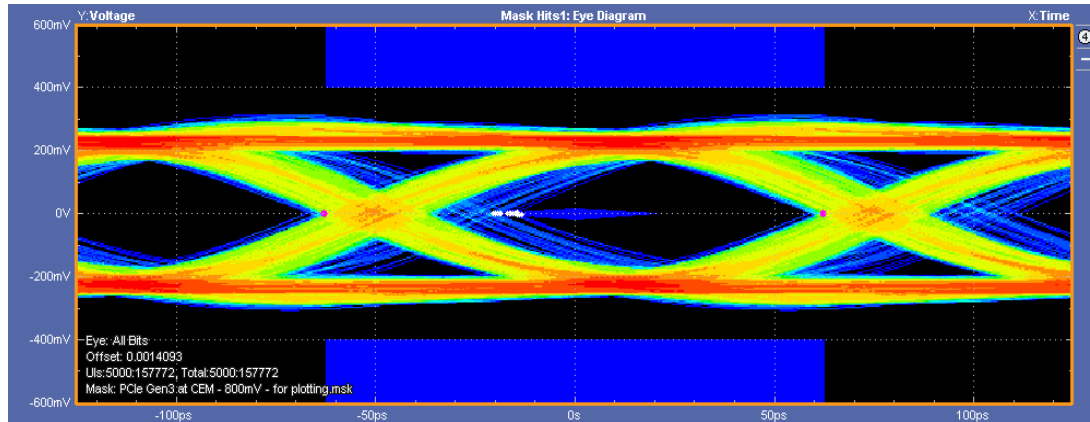
Introduction

- Mid-frequency noise (~ 100 MHz) associated with the fast switching of a switching regulator may couple onto nearby signal traces
- A case of this noise coupling in a practical server system will be explored
- \rightarrow Mid-frequency noise may be difficult to contain and understand



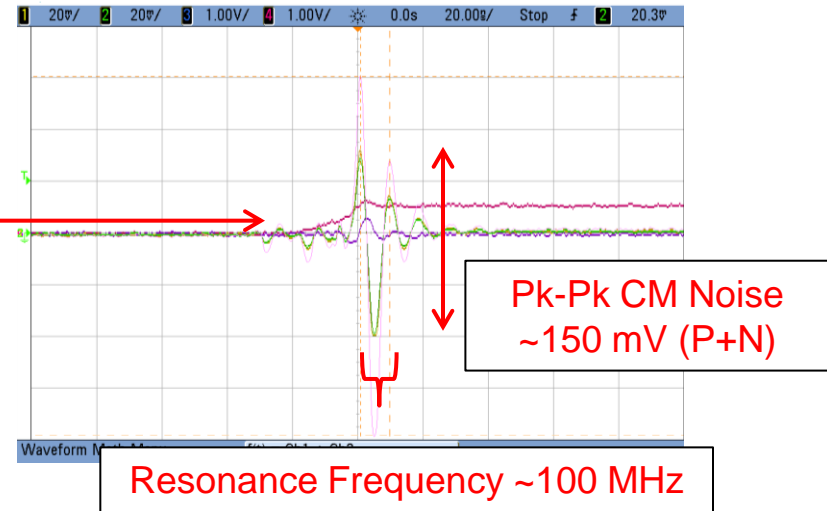
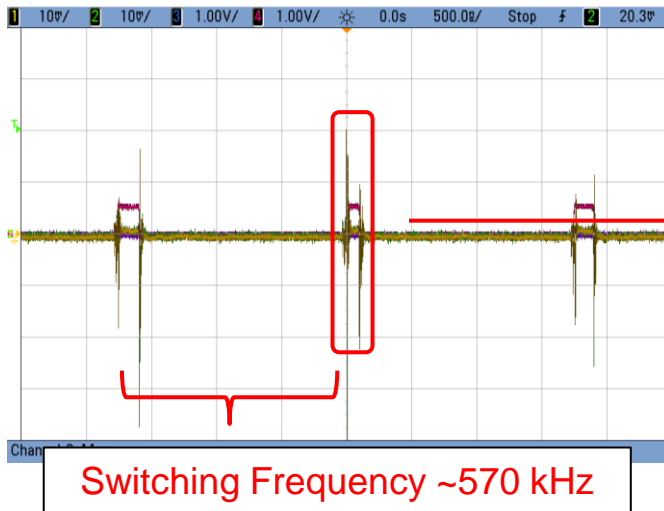
Problem Discovery: Compliance

- In a multi-processor server system, one downstream PCIe (Gen3) lane failed badly during compliance testing, but...
- Only occurred with one particular option card, in one particular slot



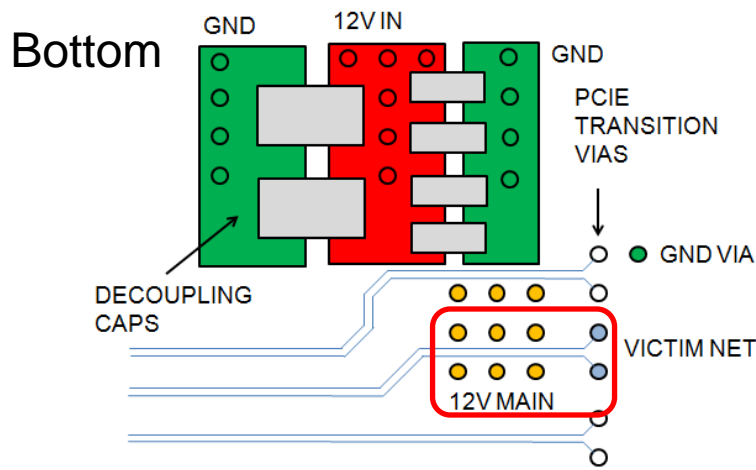
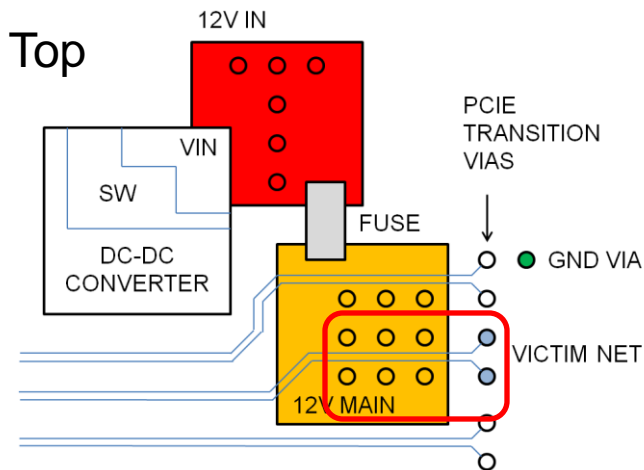
Common-Mode Noise

- When victim lane was measured on an oscilloscope, periodic common-mode noise observed during rising edge of a nearby switching regulator



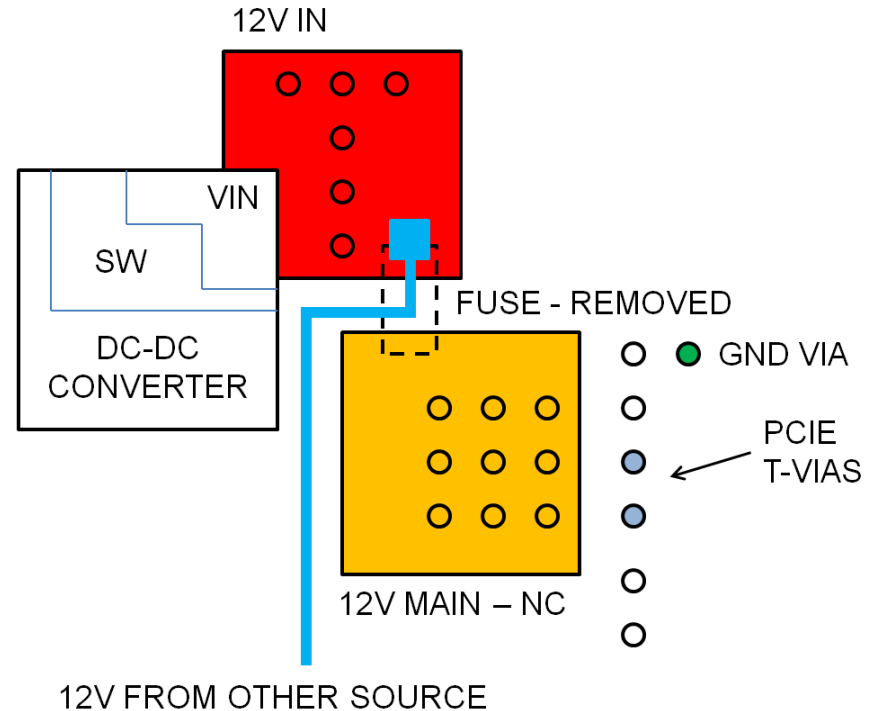
Review of Layout: Problem Area

- Victim lane routed through 12V vias input to regulator
- Reasonable to think electrical coupling from 12V vias could be causing CM noise on low-swing, high-speed signal



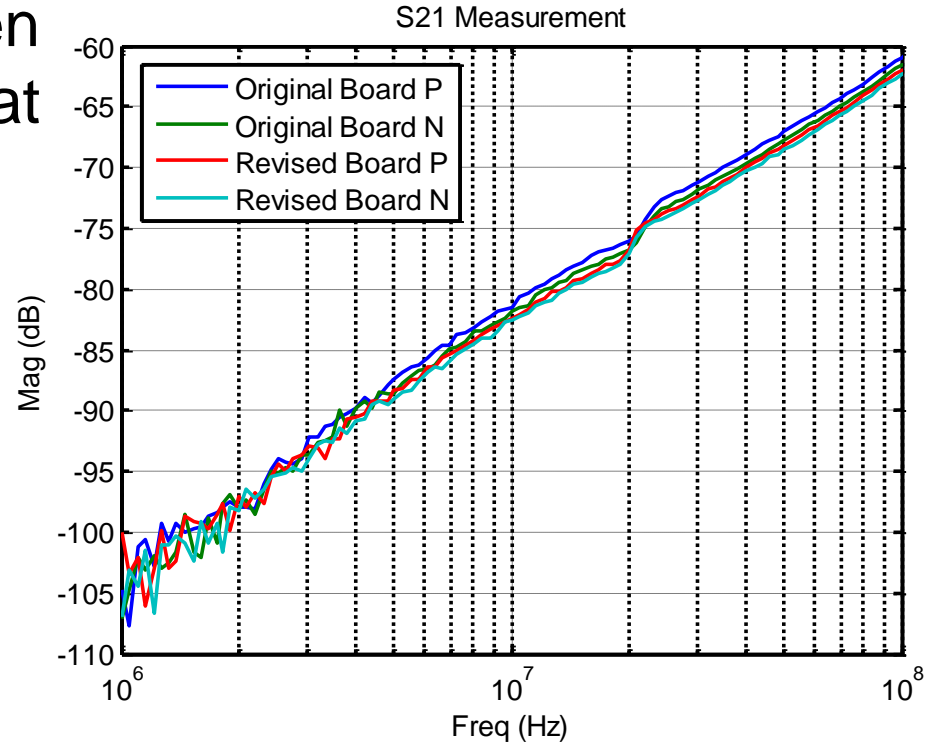
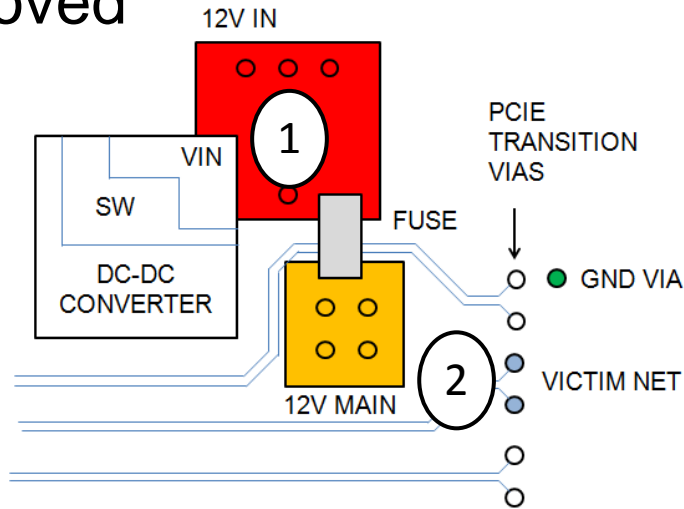
Debugging a Solution

- Bypassing fuse and supplying 12V from another source (avoiding current circulation in vias) eliminated CM noise on victim lane
- → Proved CM noise caused by routing signal traces in close proximity to 12V vias
- Implemented on next spin of board



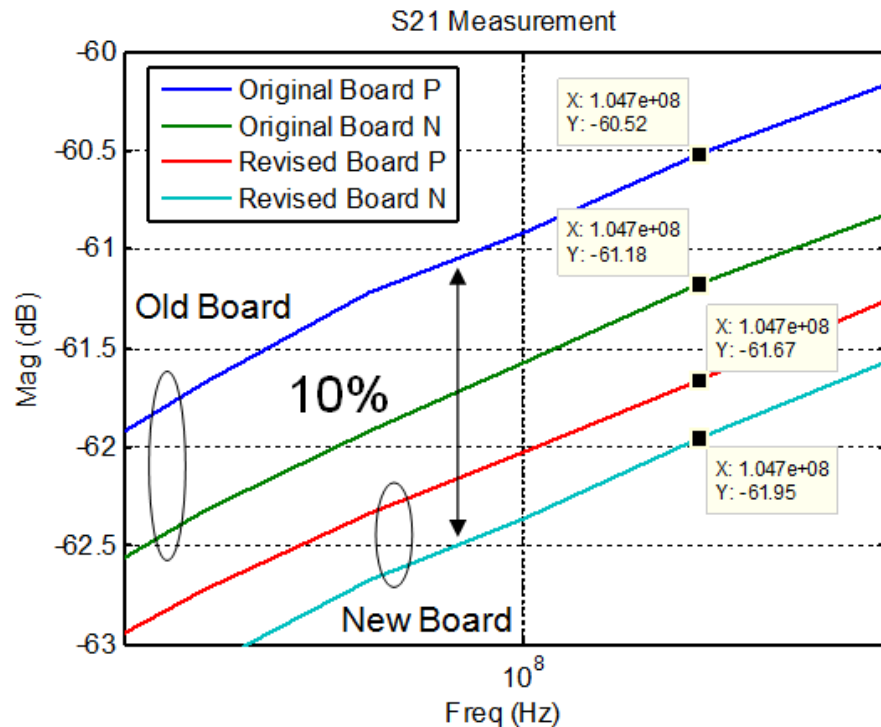
Follow-up Crosstalk Measurements

- Crosstalk measurements taken on next revision to validate that coupling mechanism was removed



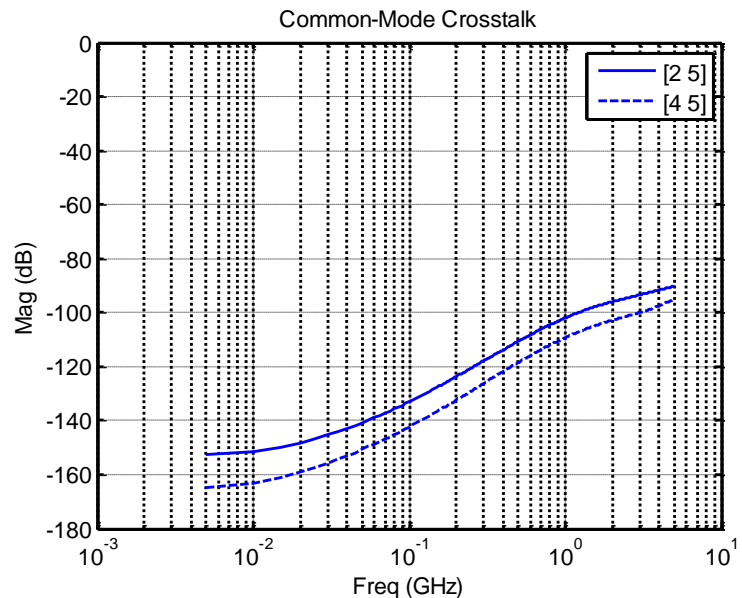
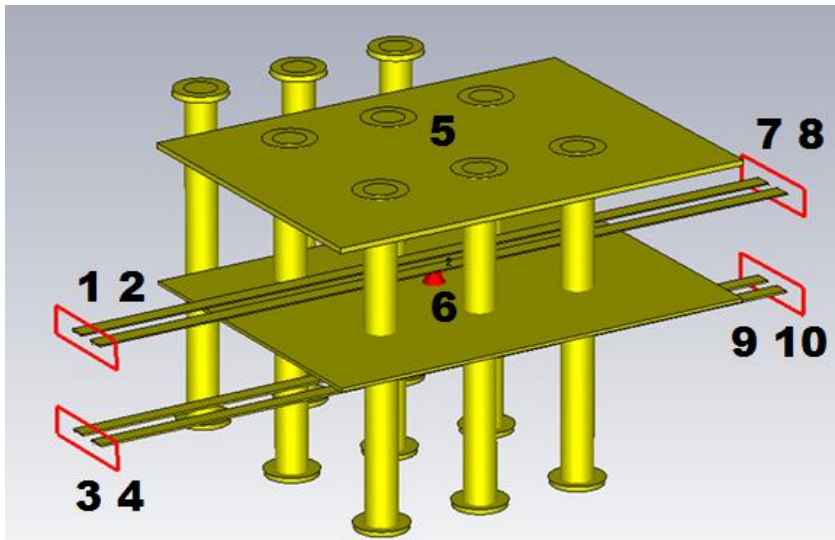
Follow-up Crosstalk Measurements

- Only a 10% improvement in crosstalk magnitude
- Coupling mechanism was not removed with layout changes!!!



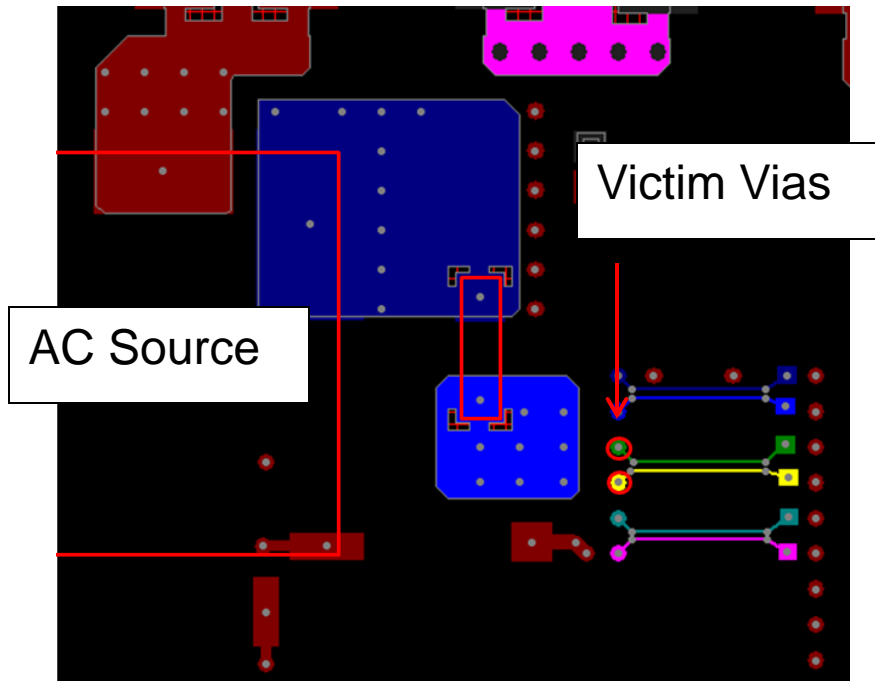
3D Field Solver Simulation

- Coupling is not capacitive (trace-to-via) but must be magnetic (loop-to-loop)



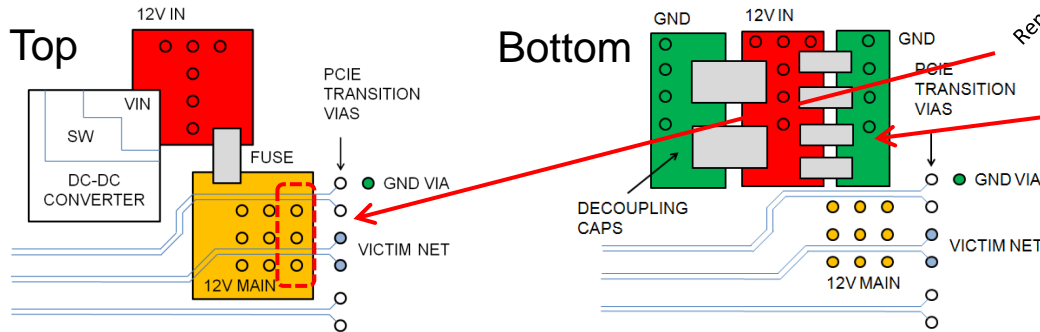
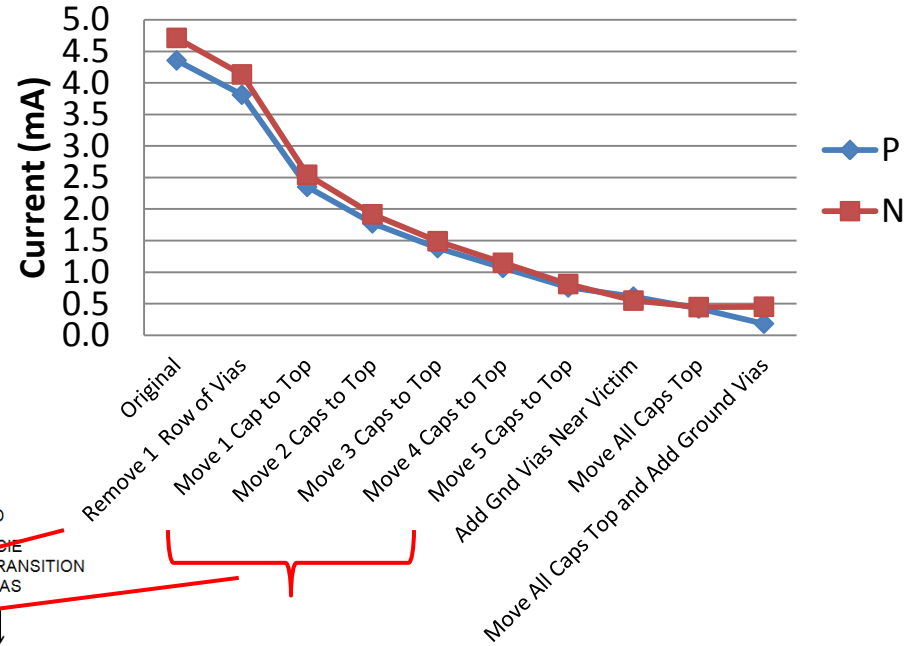
Larger Plane Simulation

- Hybrid solver set up to simulate current induced in victim vias
 - AC source with constant amplitude (17A) setup at 12V input vias of switching regulator and swept from 10 MHz – 500 MHz



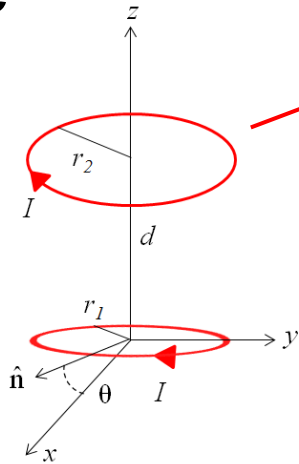
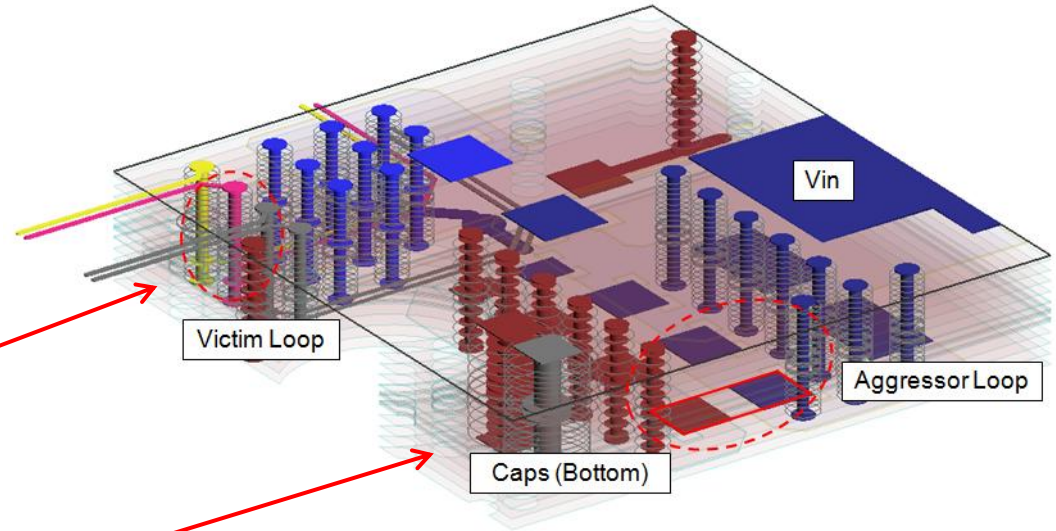
Larger Plane Simulation

- Simulation run with number of layout changes
- Results (taken at 100 MHz)
- **CAPACITORS ON THE BOTTOM**



Placing Input Capacitors on Bottom

- Caps are on the bottom
- This creates loop that is the aggressor noise source

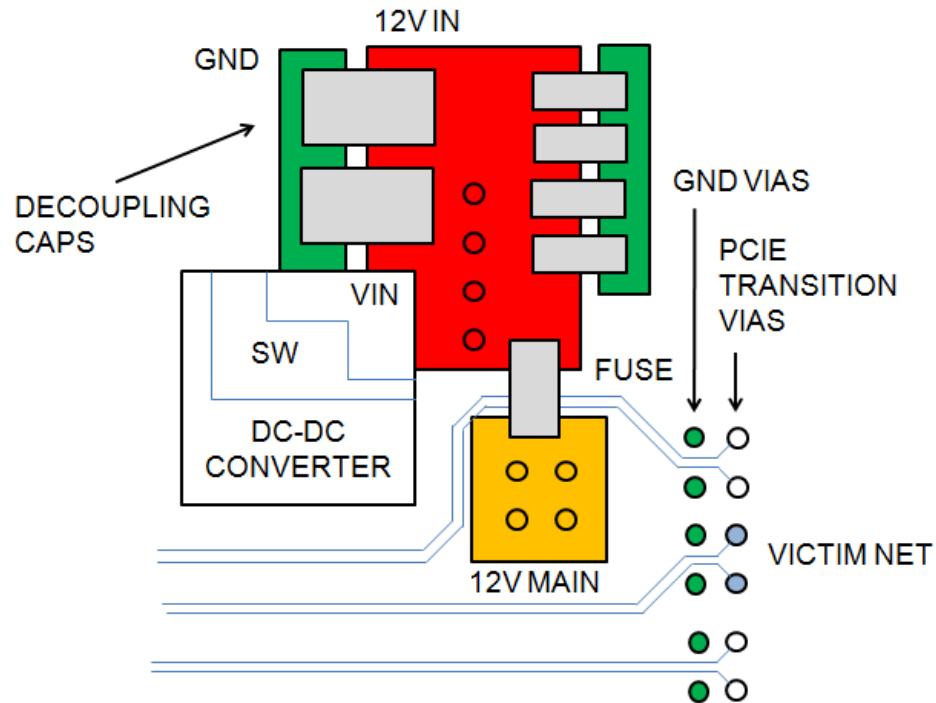


- Size of aggressor loop (r_1)
- Size of victim loop (r_2)
- Distance between the loops (d)
- Relative loop orientation (θ)



Final Revision of Board

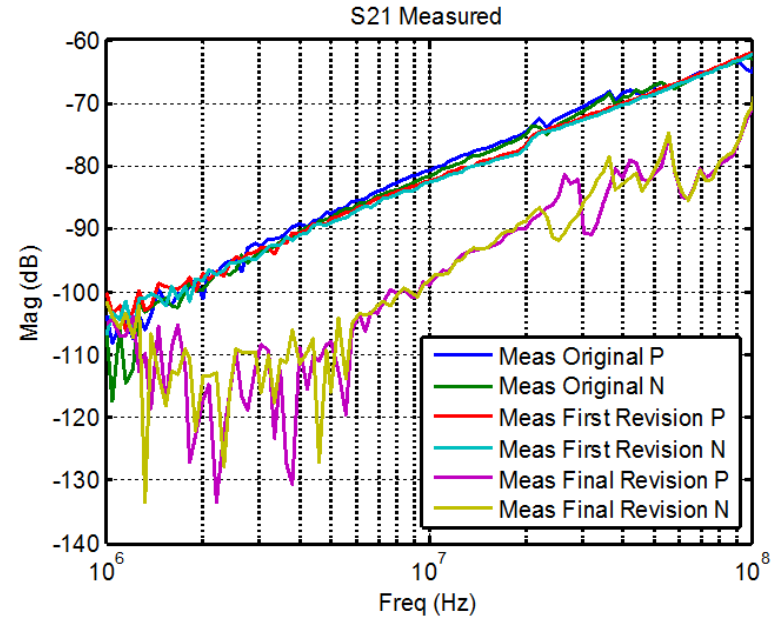
- On final board revision, added ground shielding vias and moved decoupling capacitors to the top of the board
- **We threw everything at it!!!!!!!!!!!!!!!!!!!!!!**



Proof is in the Pudding: Crosstalk Measurements

- Crosstalk measurements of final board shows significant improvement in crosstalk!!!

Case closed

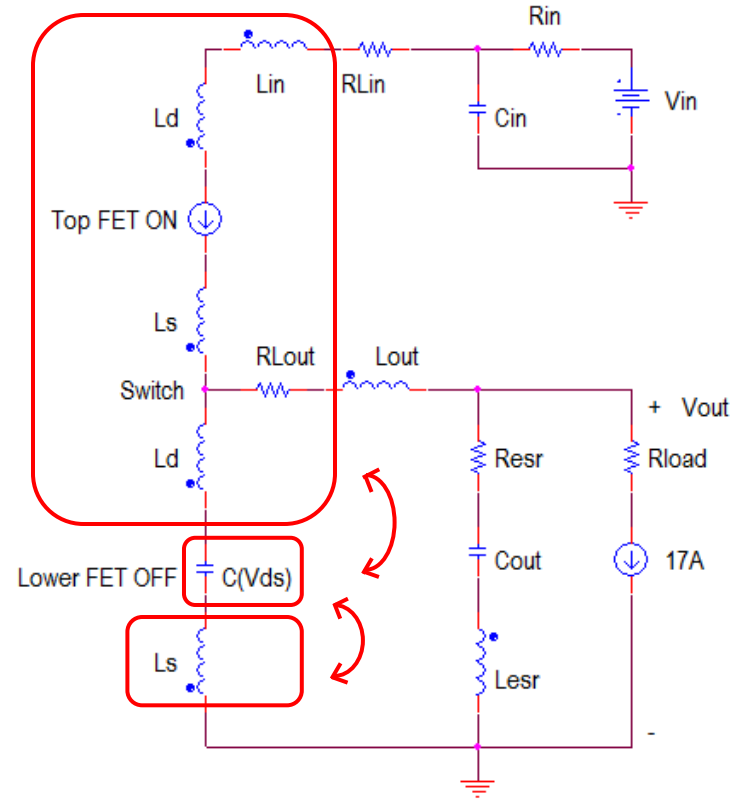


But wait, why 100MHz???



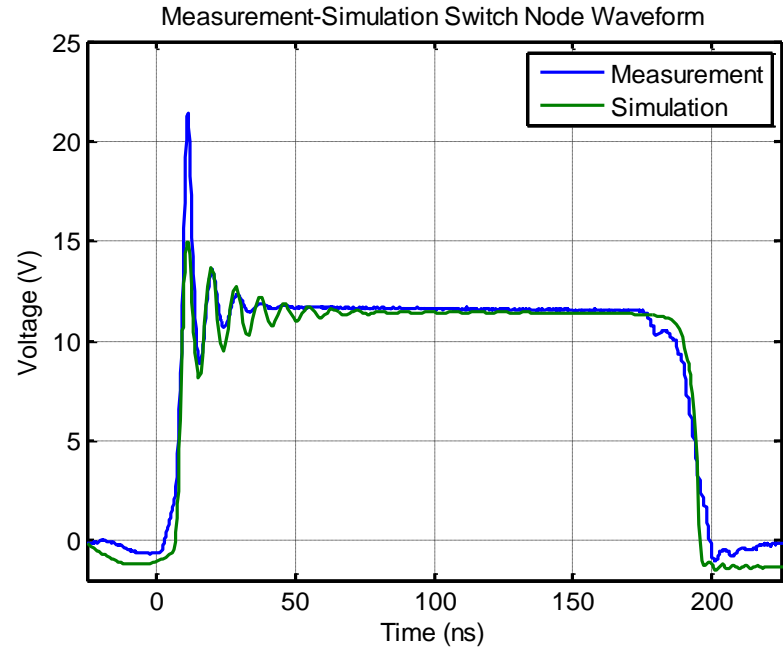
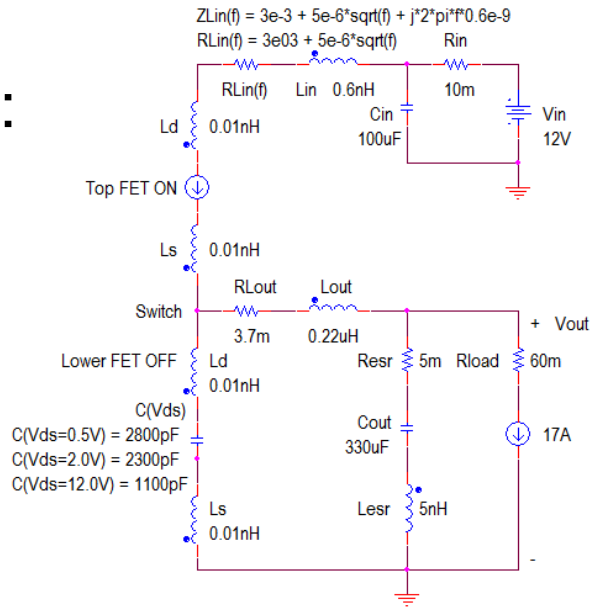
Understanding the Noise Source

- SPICE model created to simulate ringing on the rising switching waveform
- Ringing frequency (100 MHz) is a result of resonance between inductance of power path, package inductances and parasitic capacitance of low-side FET



Understanding the Noise Source

- SPICE simulation correlated to measurement taken at switch node
- Values:



Conclusion

- The source of noise in this layout was fast slew rate associated with high di/dt of switch node waveform
- On the rising edge of the switch node voltage, the resonance frequency (100 MHz) was set by the capacitance of the low-side FET, the parasitic inductance of the FETs packages, and the inductance of the supply rail feeding the DC-DC converter input
- Placing the input decoupling capacitors and the converter on opposite sides of the board creates an aggressor magnetic loop for high di/dt
- To mitigate inductive noise coupling at mid-frequencies, place decoupling capacitors and the switching devices on the same side of the board (reduce aggressor loop)
- If this can't be done, place ground vias nearby the victim vias (reduce the victim loop)!!!
- →Be careful placing signal vias near switching regulators – mid-frequency noise may travel farther than you think!!!



Acknowledgements

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Thank you!

QUESTIONS?

